

Initial Product/Process Change Notification Document #: IPCN22134XB

Issue Date: 11 April 2018

Title of Change:	Hydrazine elimination of ON Semiconductor Niigata Co., Ltd. (OSNC).		
Proposed first ship date:	4 January 2019		
Contact information:	Contact your local ON Semiconductor Sales Office or < Tetsuya.Fukushima@onsemi.com >		
Samples:	Contact your local ON Semiconductor Sales Office.		
Type of notification:	This is an Initial Product/Process Change Notification (IPCN) sent to customers. IPCNs are issued at least 30 days prior to the issuance of the Final Change Notice (FPCN). An IPCN is an advance notification about an upcoming change and contains general information regarding the change details and devices affected. It also contains the preliminary reliability qualification plan. The completed qualification and characterization data will be included in the Final Product/Process Change Notification (FPCN). This IPCN notification will be followed by a Final Product/Process Change Notification (FPCN) at least 90 days prior to implementation of the change. In case of questions, contact <pcn.support@onsemi.com>.</pcn.support@onsemi.com>		
Change Part Identification:	Date Code		
Change category:	■ Wafer Fab Change	Test Change Other	
Change Sub-Category(s): ☐ Manufacturing Site Change/Addition ☐ Manufacturing Process Change ☐ Manufacturing Process Change		☐ Datasheet/Product Doc change ☐ Shipping/Packaging/Marking ☐ Other:	
Sites Affected:	ON Semiconductor Sites: ON Niigata, Japan	External Foundry/Subcon Sites: None	

Description and Purpose:

 $This \ Initial\ notification\ announces\ the\ elimination\ of\ Hydrazine\ in\ ON\ Semiconductor\ Niigata\ Co.,\ Ltd.\ (OSNC)\ Japan\ for\ parts\ listed\ in\ this\ PCN.$

The related products are transferred to a process that does not use Hydrazine on the same site OSNC.

Change Point	Before Change Description	After Change Description	
Fab (OSNC)	N1 Fab (Minimum rule=0.8um, Class=100)	N1 Fab (Minimum rule=0.8um, Class=100) AND N2 Fab (Minimum rule=0.25um, Class=10)	
Wire material	Aluminum (without Anti-reflected Layer)	Aluminium (with Anti-reflected Layer)	
Interlayer material Silicon nitride and Polyimide or Polyimide		Silicon nitride and Silicon oxide or Oxide	

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Qualification Plan:

QV DEVICE NAME: LB11870-TRM-E PACKAGE: HSSOP48 (375 mil)

Test	Specification	Condition	Interval
HTOL	JESD22-A108	Tj=150°C, 100 % max rated Vcc	1008 hrs
HTSL	JESD22-A103	Ta= 150°C	1008 hrs
TC	JESD22-A104	Ta= -65°C to +150°C	500 cyc
THB	JESD22-A101	85°C, 85% RH, bias	1008 hrs
uHAST	JESD22-A118	130°C, 85% RH, 18.8psig,	96 hrs
PC	J-STD-020 JESD-A113	MSL3 @ 260 ℃	-
НВМ	JS001	100pF,1.5kohm	-
CDM	JS002		-

List of Affected Standard Parts:

Part Number	Qualification Vehicle
LA6585MC-AH-M	LB11870-TRM-E
LA4814JA-AE	
LA4815VH-TLM-H	
LA5757TP-TL-E	
LB11852FV-W-AH	

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Appendix A: Changed Products

Product	Customer Part Number	Qualification Vehicle
LA4814JA-AE		LB11870-TRM-E
LA4815VH-TLM-H		LB11870-TRM-E
LA5757TP-TL-E		LB11870-TRM-E
LB11852FV-W-AH		LB11870-TRM-E